AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-334-8648

Inclosure Material:	
Ceramic	
Overall Length:	
Between 0.660 inche	es and 0.785 inches
Terminal Length:	
0.300 inches	
Overall Height:	
0.200 inches	
Overall Width:	
Between 0.220 inche	es and 0.280 inches
Component Name	And Quantity:
4 transistor	
Mounting Method:	
Terminal	
Features Provided:	
Electrostatic sensitiv	e
Semiconductor Mat	terial:
Silicon all transistor	
Voltage Rating In V	olts Per Characteristic:
30.0 collector to em	itter voltage/static/base open all transistor and 60.0 collector to base voltage/static/emitter open all transistor and 5.0
emitter to base voltage	ge, static, collector open all transistor
Current Rating Per	Characteristic:
300.00 milliamperes	source cutoff current all transistor
Power Rating Per C	Characteristic:
1.9 watts small-signa	al input power, common-collector absolute all transistor
Maximum Operatin	g Tempurature Per Measurement Point:
200.0 degrees celsiu	is junction
Special Features:	
All transistor junction	n pattern arrangement: npn
Terminal Type And	Quantity:
14 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	